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MAGX-000035-030000





GaN HEMT Power Transistor 30W CW, 30 MHz - 3.5 GHz

Features

- GaN depletion mode HEMT microwave transistor
- Common source configuration
- No internal matching
- Broadband Class AB operation
- Thermally enhanced Cu/Mo/Cu package
- RoHS Compliant
- +50V Typical Operation
- MTTF of 114 years (Channel Temperature < 200°C)

Applications

General purpose for pulsed or CW applications

- Commercial Wireless Infrastructure
 WCDMA, LTE, WIMAX
- Civilian and Military Radar
- Military and Commercial Communications
- Public Radio
- Industrial, Scientific and Medical
- SATCOM
- Instrumentation
- Avionics

Product Description

The MAGX-000035-030000 is a gold metalized unmatched Gallium Nitride (GaN) on Silicon Carbide RF power transistor suitable for a variety of RF power amplifier applications. Using state of the art wafer fabrication processes, these high performance transistors provide high gain, efficiency, bandwidth, ruggedness over multiple octave bandwidths for today's demanding application needs. The MAGX-000035-030000 is constructed using a thermally enhanced Cu/Mo/Cu flanged ceramic package which provides excellent thermal performance. High breakdown voltages allow for reliable and stable operation in extreme mismatched load conditions unparalleled with older semiconductor technologies.

Technology Solutions

Typical CW RF Performance

Freq. (MHz)	Pout (W Ave)	Gain (dB)	Eff (%)
30	58	40	80
100	44	32	65
500	43	27	66
1500	42	20	59
3000	35	13	55
3500	30	12	53

Ordering Information

MAGX-000035-030000 MAGX-000035-SB1PPR 30W GaN Power Transistor 1.5 GHz Evaluation Board

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Absolute Maximum Ratings (1, 2, 3)	Limit			
Supply Voltage (Vdd)	+65V			
Supply Voltage (Vgg)	-8 to 0V			
Supply Current (Id1)	1200 mA			
Input Power (Pin)	+30 dBm			
Junction/Channel Temp	200 °C			
MTTF (TJ<200°C)	114 years			
Continuous Power Dissipation (Pdiss) at 85 °C	27 W			
Pulsed Power Dissipation (Pavg) at 85 °C	65 W			
Thermal Resistance, (Tchannel = 200 °C), CW	4.2 °C/W			
Thermal Resistance, (Tchannel = 200 °C), Pulsed 500uS, 10% Duty cycle	1.8 °C/W			
Operating Temp	-40 to +95C			
Storage Temp	-65 to +150C			
ESD Min Machine Model (MM)	50 V			
ESD Min Human Body Model (HBM)	>250 V			

(1) Operation of this device above any one of these parameters may cause permanent damage.

(2) Channel temperature directly affects a device's MTTF. Channel temperature should be kept as low as possible to maximize lifetime.

(3) For saturated performance it recommended that the sum of (3*Vdd + abs(Vgg)) <175

Parameter	Test Conditions	Symbol	Min	Тур	Max	Units
DC CHARACTERISTICS						
Drain-Source Leakage Current	V _{GS} = -8V, V _{DS} = 175V	I _{DS}	-	-	2.5	mA
Gate Threshold Voltage	$V_{DS} = 5V, I_D = 6mA$	V _{GS (th)}	-5	-3	-2	V
Forward Transconductance	$V_{DS} = 5V, I_D = 1.5mA$	G _M	1.0	-	-	S
DYNAMIC CHARACTERISTICS						
Input Capacitance	V_{DS} = 0v, V_{GS} = -8V, F = 1MHz	C _{ISS}	_	13.2	-	pF
Output Capacitance	V_{DS} = 50V, V_{GS} = -8V, F = 1MHz	C _{oss}	-	5.6	-	pF
Reverse Transfer Capacitance	V_{DS} = 50V, V_{GS} = -8V, F = 1MHz	C _{RSS}	-	0.5	-	pF

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Electrical Specifications: $T_c = 25 \pm 5^{\circ}C$ (Room Ambient)

Parameter	Test Conditions	Symbol	Min	Тур	Мах	Units
RF FUNCTIONAL TESTS Vdd=50V, Idq= 100 mA, single frequency optimized data						
CW Output Power (P2dB) 1 .5GHz	Pin = 1W Ave	P _{OUT}	30	42	-	W Ave
CW Output Power (P2dB) 3 GHz	Pin = 1W Ave	P _{OUT}	30	31	-	W Ave
Small Signal Gain @ 1.5 GHz	Pout = 5W Ave	G _P	18	20		dB
Small Signal Gain @ 3 GHz	Pout = 5W Ave	G _P	13	13.6		dB
Drain Efficiency @ 3 GHz	Pin = 1W Ave	η_{D}	50	60		%
Load Mismatch Stability	Pin = 1W Ave	VSWR-S	5:1	-	-	-
Load Mismatch Tolerance	Pin = 1W Ave	VSWR-T	10:1	-	-	-

Test Fixture Impedance

F (MHz)	Zif-opt (Ω)	Zof-opt (Ω)	
30	71 + j 255	24.9 - j 6.8	
100	7.7 + j 66.6	22.14 - j 4.33	
500	3.19 + j 13.8	21.8 + j 9.94	
1500	1.4 + j 0.16	9.31 + j 9.34	
3000	3.1 - j 9.96	3.32 + j 1.2	
3500	TBD	TBD	



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GaN HEMT Power Transistor 30W CW, 30 MHz - 3.5 GHz

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1.5 GHz Test Fixture Circuit Dimensions



1.5 GHz Test Fixture Assembly



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3 GHz Test Fixture Circuit Dimensions



3 GHz Test Fixture Assembly



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Outline Drawings



CORRECT DEVICE SEQUENCING

TURNING THE DEVICE ON

- 1. Set V_{GS} to the pinch-off (V_P), typically -5V
- 2. Turn on V_{DS} to nominal voltage (50V)
- 3. Increase V_{GS} until the I_{DS} current is reached
- 4. Apply RF power to desired level

TURNING THE DEVICE OFF

- 1. Turn the RF power off
- 2. Decrease V_{GS} down to V_P
- 3. Decrease V_{DS} down to 0V
- 4. Turn off V_{GS}

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